

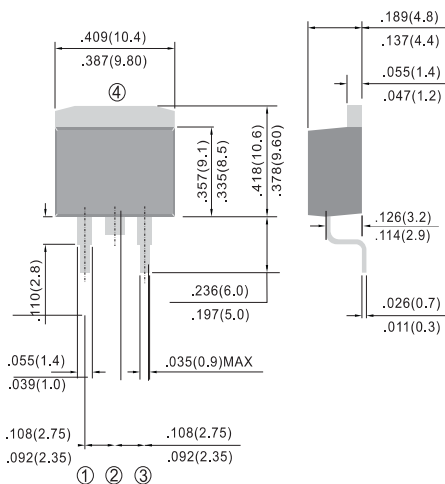
## 20.0 AMPS. Schottky Barrier Rectifiers

### Features:

- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guardring for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case

### Mechanical Data:

- ✧ Cases: JEDEC TO-263 molded plastic
- ✧ Terminals: Leads solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)



### Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

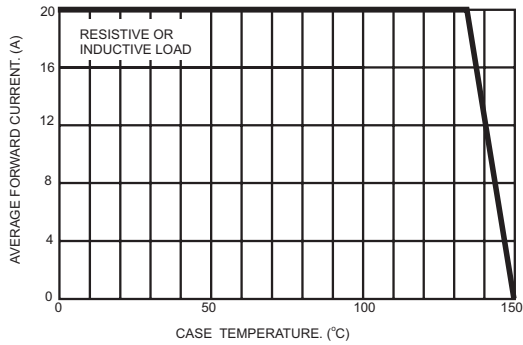
For capacitive load, derate current by 20%

Type Number	Symbol	MBRB20 45CT	MBRB20 60CT	MBRB20 100CT	MBRB20 150CT	MBRB20 200CT	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	45	60	100	150	200	V
Maximum RMS Voltage	$V_{RMS}$	31	42	70	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	45	60	100	150	200	V
Maximum Average Forward Rectified Current at $T_C=135^\circ\text{C}$	$I_{(AV)}$	20					A
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20KHz) at $T_C=135^\circ\text{C}$	$I_{FRM}$	20.0					A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	150					A
Peak Repetitive Reverse Surge Current (Note 1)	$I_{RRM}$	1.0	0.5		1.0		A
Maximum Instantaneous Forward Voltage at (Note 2) IF=10A, TC=25°C IF=10A, TC=125°C IF=20A, TC=25°C IF=20A, TC=125°C	$V_F$	0.52 0.57 0.84 0.72	0.80 0.70 0.95 0.85	0.85 0.75 0.95 0.85	0.99 0.87 1.23 1.10	V	
Maximum Instantaneous Reverse Current @ $T_C=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_C=125^\circ\text{C}$	$I_R$	0.1	0.15		0	2	mA mA
Voltage Rate of Change, (Rated $V_R$ )	$dV/dt$	10,000					V/μs
Typical Junction Capacitance	$C_j$	400	320				pF
Typical Thermal Resistance Per Leg (Note 3)	$R_{\theta JC}$	1.0			2.0		°C/W
Operating Junction Temperature Range	$T_J$	-65 to +150					°C
Storage Temperature Range	$T_{STG}$	-65 to +175					°C

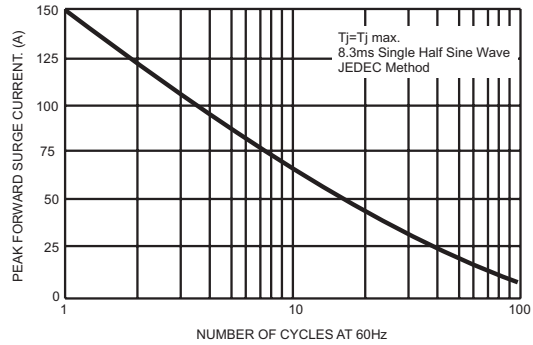
Notes: 1. 2.0us Pulse Width,  $f=1.0$  KHz  
 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle  
 3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate.

**RATINGS AND CHARACTERISTIC CURVES (MBRB2045CT THRU MBRB20200CT)**

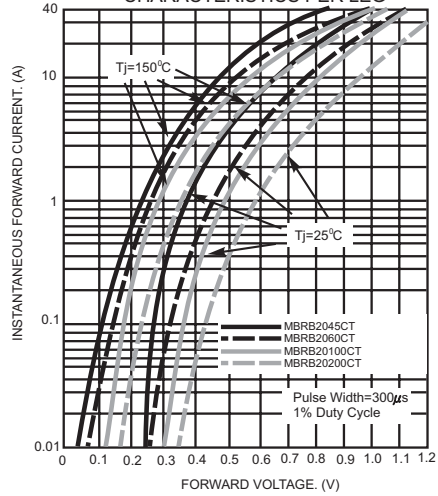
**FIG.1- FORWARD CURRENT DERATING CURVE**



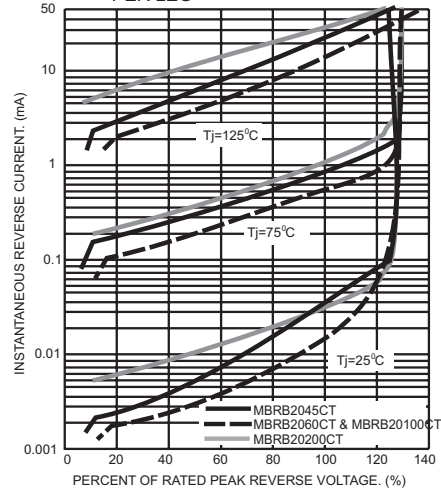
**FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG**



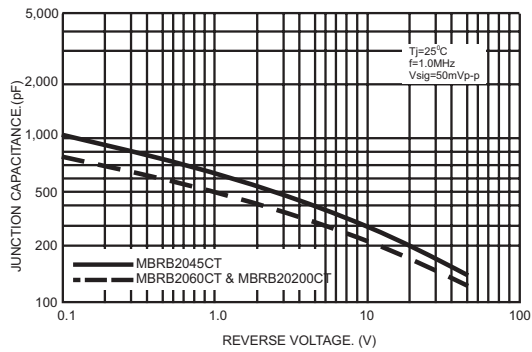
**FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG**



**FIG.4- TYPICAL REVERSE CHARACTERISTICS PER LEG**



**FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG**



**FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG**

